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1. Implementation

1.1 Laser module

1.1.1 Laser

The laser plays one of the key role in the whole system. Strict requirements are imposed on it, starting from the pulse energy, ending with the generation stability. The maximum distance at which we can detect an object directly depends on the pulse energy, in our case the energy should be more than 1 uJ to reach 200m distance. To get a picture in good pixel resolution, especially at high FPS, we need a fairly fast pulse repetition rate, at least 10kHz. Using the TOF method it is extremely important to have a small pulse width, the smaller, the smaller the measurement error and the higher the accuracy. To obtain acceptable accuracy, the pulse width should be less than 10 ns and have a Gaussian-like shape, moreover timing jitter should be as small as possible. The wavelength of the laser should coincide with the receiver spectrum for better amplification, in the case of SiPM it is around 420 nm. Being used in space, reability, size and power consumption become critical.

Finaly, the requriments for laser is:

| Pulse energy: | \geq 1 uJ |
|--------------------|--------------------------|
| Repetition rate: | \geq 10 kHz |
| Pulse duration: | ≤ 10 ns |
| Wavelength, λ: | depends on SNR, <1000nm |
| Power consumption: | ≤ 2 W |
| Dimension: | \leq 3 cm ³ |

Table 1.1. Requirements for the laser system

Nowadays, there are a lot of laser solutions: Solid-state lasers, Semiconductor lasers, Fiber lasers, Gas lasers, but many of them do not meet all our requirements. Solid-state lasers can be used in a pulsed

mode with Q-switching (active or passive) technique and also in Mode-locking mode. In the case of the Mode-locking mode, the repetition frequency can reach many MHz, whereas the pulse duration is much lower: typically between 30 fs and 30 ps. Despite the complexity of creation such laser, the energy of the pulse, is extremely small and can not be used for our purposes.

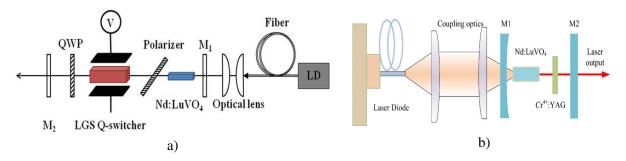


Fig. 1.1. Typical Q-switched schemes for active and passive mode: a) Laser diode end-pumped actively Q-switched laser utilizing a langasite (LGS) crystal as an electro-optic Q-switch. b) High repetition rate laser-diode end-pumped passively Q-Switched Nd:LuVO4/Cr4+:YAG

In case of Q-switched lasers (Fig. 1.1), the pulse repetition rate is typically in the range from 1–100 kHz, sometimes higher. Passively Q-switched microchip lasers have reached pulse durations far below 1 ns and repetition rates up to several megahertz, whereas large (typically amplified) laser systems can deliver pulses with many kilojoules of energy and durations in the nanosecond range. For active Qswitching, the losses are modulated with an active control element (active Q-switch), typically either an acousto-optic or electro-optic modulator. Here, the pulse is formed shortly after an electrical trigger signal arrives. There are also mechanical Q-switches such as spinning mirrors, used as end mirrors of laser resonators. In any case, the achieved pulse energy and pulse duration depends on the energy stored in the gain medium, i.e. on the pump power and the pulse repetition rate. For passive Q-switching (sometimes called self Q-switching), the losses are automatically modulated with a saturable absorber. Here, the pulse is formed as soon as the energy stored in the gain medium (and thus the gain) has reached a sufficiently high level. In many cases, the pulse energy and duration are then fixed, and changes of the pump power only influence the pulse repetition rate. Compared with active Q-switching, passive Q-switching is simple, takes up little space and cost-effective (eliminating the modulator and its electronics), and is suitable for very high pulse repetition rates. However, the pulse energies are typically lower. Unfortunatelly, closest for our wavelength interset are based on a neodymium-doped laser crystal which are applicable for Q-switching lay in the wavelength range ~ 1 um, such as Nd:YVO4/Cr4+:YAG

914 nm [1][2], Nd:GdVO4/Cr4+:YAG 912 nm [3][4], Nd:LuVO4/Cr4+:YAG 916 nm [5]. Due to the size of laser system, the best solution is passive Q-switched microchip laser: alignment-free monolithic solid-state laser where the laser crystal (or glass) is directly contacted with the end mirrors of the laser resonator (Fig. 1.2).

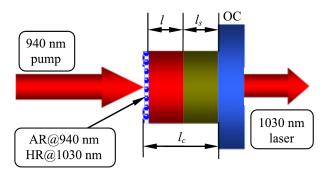


Fig. 1.2. The experimental setup of laser-diode pumped Yb:YAG/Cr:4+:YAG composite ceramics passively Q-switched laser. OC is the output coupler.

Q-switched microchip lasers also allow the generation of unusually short pulses with durations below 1 ns, in extreme cases even below 100 ps. This holds particularly for passive Q switching with a SESAM [2], but it is also possible to use a saturable absorber crystal e.g. of Cr:YAG or some Cr-doped ceramics [1].

Eventually according to numerical simulation [1,2] the minimum pump power for high-repetition laser system, which is satisfied our requrements is quite big > 6-8W this is just for start trigger lasing at 10kHz (for Nd:YVO4/Cr4+ with best transmission parameters). This is because, optical-to-optical efficiencies – typically of the order of 5-20%. At the same time, electrical-to-optical efficiencies sometimes even above 60%.

Therefore, we are trying to use a laser diode. Fortunately there is powerful high-repetition rate laser diode with quite short pulse duration $\sim 10ns$ at 905 nm from OSRAM Opto Semiconductors (Fig. 1.3). Despite the fact that the amplification of the detector at this wavelength is small, the laser power exceeds these losses, moreover at this wavelength the noise is smaller. Also it is eye-safe, that expand spectrum of possible applications.



Fig. 1.3. Osram laser diode

| Peak output power: | $75\pm10~\mathrm{W}$ |
|----------------------------------|----------------------|
| Forward current: | 40 A |
| Repetition rate: | \sim 100 kHz |
| Pulse duration: | ≥ 10 ns |
| Emission wavelength, λ : | 905 \pm 10 nm |
| Rise time: | 1 ns |
| Fall time: | 1 ns |
| Emmiting area: | 200 x 10 um |
| Beam divergence: | 25° x 9° |
| Operating temperature: | -40 100 °C |

Table 1.2. OSRAM Laser diode characteristics

1.1.2 Laser collimator

Radiation characteristic of laser diode features carries due to its small size, light quality, low threshold, low cost, these properties the laser diode play an important role in the information time, especially in the field of communication LIDAR. Optical system is an essential part, which plays an important role in decreasing the divergence angle and homogenizing the beam spot which have an immense influence on the light signal back from the target. Together with the detector's collimator, a system with high resolution and high SNR can be obtained. The design of the system was done by using ZEMAX model which also includes shaping and zooming features of design model.

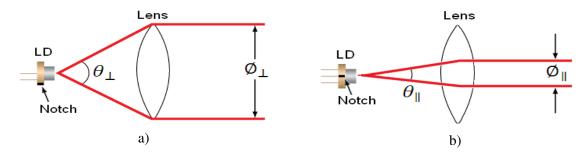


Fig. 1.4. In the above schematics, LD denotes the laser diode, $\emptyset_{||}$ and \emptyset_{\perp} are the beam diameters in the parallel and perpendicular orientations, respectively, and $\theta_{||}$ and θ_{\perp} are the divergence angles in the parallel and perpendicular orientations, respectively.

a) Perpendicular beam divergence from laser diode. b) Parallel beam divergence from laser diode.

The beam divergences of an edge-emitting laser diode will be different in the parallel and perpendicular directions, leading to an elliptical beam (Fig. 1.4). This can be compensated for by inserting anamorphic prism pairs or cylindrical lenses into the collimated beam, but in our case it's not needed.

Since the output of a laser diode is highly divergent, collimating optics are necessary. Traditional

spherical lenses have a simple shape that can be described as an arc of a circle and can be specified using only a radius of curvature. Although these lenses are simple to manufacture and inexpensive to use, they suffer in performance due to a phenomenon called spherical aberration. This inherent defect is due to the fact that a spherical shape is not the ideal shape for a focusing or collimating lens to be. The ideal case is a more complex shape that is typically defined using a radius of curvature, a parabolic term (conic), and several high order coefficients. The complex shape of aspheric lenses allows for correction of spherical aberration. This provides better quality collimated beams for collimating applications, a smaller spot size for focusing applications, and better image quality for imaging applications. In fact, in many cases just a single aspheric lens can take the place of several conventional spherical lenses, leading to a lighter, more compact, less expensive, and better performing optical system. Aspheres are now a viable design option for many applications. Choosing an appropriate aspheric lens for collimating a laser diode is essential, as the resulting beam size and transmission range are dependent on the lens used.

To calculate the beam size of a collimated laser diode, we first need to know its divergences and area of emitting surface. The specifications for the OSRAM laser diode indicate that the perpendicular and parallel beam divergences are 25° and 9°, respectively. Because of this asymmetry in the two axes, an elliptical beam will form as the light diverges. To collect as much light as possible during the collimation process, consider the larger of these two divergence angles in any calculations (i.e. 25°).

In paraxial approximation, for beam diameter calculation after passing lens the following formula is using (Fig. 1.4):

$$\emptyset_{\perp} = 2 \cdot f \cdot \tan\left(\frac{\theta_{\perp}}{2}\right)$$
(1.1)

For beam divergence after passing the optical system (Fig. 1.5):

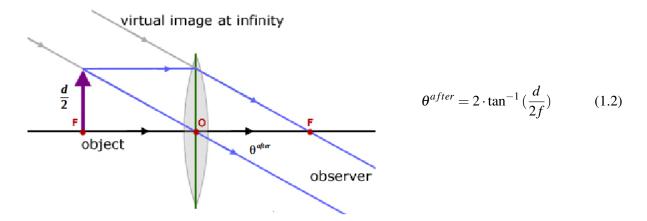


Fig. 1.5. Simple demonstration, shows divergence of the beam emitted from object, seated at the focus of the optical system. Here, d is the size of emitting area of laser diode (200 um in our case), f is total focal length of the optical system.

From the formulas 1.1 1.3, it is obvious that the larger the focal lens, the larger the diameter of the beam and the smaller the beam divergence. It means, that by increasing focal length we can achieve the desirable level of divergence (up to diffraction limit, with assumption we free of aberrations). But, by increasing focal length the beam diameter is also increased. Since the size of MEMS is only 3.5 mm, we have limitation for focal length (we want reflect all light which are emitted). The same result can be getting from the Lagrange invariant relationship between the heights and angles of any two rays propagating through the system (in case of linearity of paraxial optics).

Important to note, that even a well-collimated beam has a non-vanishing divergence because of wavenature of the light, the beam diameter varies (for large distances) with the distance from the laser diode collimator. The resulting beam divergences of the collimated beam:

$$\theta_{\perp/||} = \frac{2 \cdot \lambda}{\pi \cdot \emptyset_{\perp/||}} \tag{1.3}$$

According to formula 1.1, our focal length should be ~ 6.5 mm. The nearest suitable aspherical lens has focal length 6.2 mm (Fig. 1.6). These laser molded aspheric lense fulfilled all our the needs. By utilizing a single aspheric lens, the need for a multi-lens system is eliminated, allowing for a more compact and robust design. This aspheric lens is anti-reflection coated for optimum transmission in the 600 - 1050 nm wavelength range. The anti-reflection coating provides <0.4% average reflection over the entire design wavelength range.



Fig. 1.6. Aspheric lens used for laser collimator

| Effective Focal length: | 6.2 mm | |
|-------------------------|----------------------|--|
| Clear Aperture: | 3.7 mm | |
| Numerial aperture (NA): | 0.3 | |
| Material: | D-ZK3 | |
| Center Thickness: | 3.484 mm | |
| Coating: | BBAR (600 - 1050 nm) | |

Table 1.3. Aspheric lens characteristics



mator

| Effective Focal length: | 8 mm | 12 mm |
|-------------------------|-------------------------|--------|
| Clear Aperture: | 4 mm | 5.4 mm |
| Numerial aperture (NA): | 0.31 | 0.25 |
| Material: | N-BK7 | N-BK7 |
| Center Thickness: | 3 mm | 2.2 mm |
| Coating: | BBAR (600 - 1050 nm) | 12 mm |

Fig. 1.7. Two cylindrical lens used for laser colli- Table 1.4. Two cylindrical lens characteristics (for each axis)

The second way is using two cylindrical lenses for each axis separately (Fig. 1.7). This allows the use of a lens with a large focal length, because the divergence of the parallel axis is 9°, not 25°.

Once the analytical calculations are completed, and the system variables are determined, the ZEMAX optical design program is used to simulate a specific example. ZEMAX is a design software containing features and tools to design, optimize, and analyze any optical system.

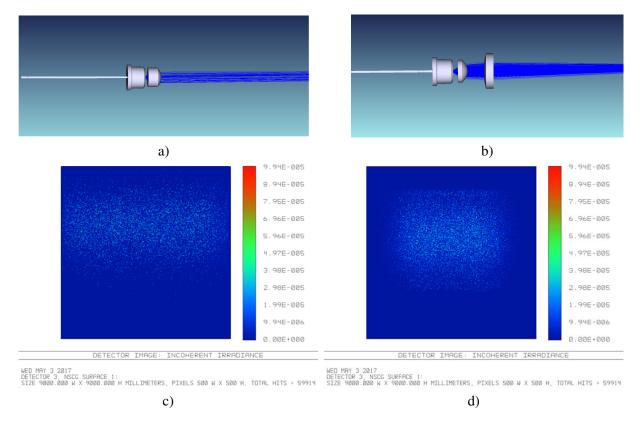


Fig. 1.8. The ray tracing and also beam spots results are obtained using non-sequential Zemax mode, the laser diode was simulated based on real ray-data file (5M rays) from OSRAM site. a) The ray traycing for sinle-lens collimator. b) The ray traycing for two-lens collimator. c) Spot diagram for sinle-lens collimator. d) Spot diagram for two-lens collimator.

The ray tracing results obtained using ZEMAX are presented in (Fig. 1.8.a)) for the single-lens system and in (Fig. 1.8.b)) for the two-lens system. Beam spots obtained with ZEMAX are presented in (Fig. 1.8.c)) and (Fig. 1.8.d)) for the single-lens and two-lens systems, respectively. As can be seen, in the case of a system of two lenses, the beam has a smaller divergence, as expected. But, a first design method seems to be more practical than the second one, since there is only one lens, and it might be easier to align a single-lens system than to align a two-lens system. However, the two-lens system has more degrees of freedom, and therefore, the optical parameters can be more widely adjusted. Also considering the size of it, it may get bulky and hard to use.

Therefore, as a compact collimator a single-lens collimator used, whose length is 10 mm, and diameter 6 mm. This colimator provide beam angular size is 0.1° x 2.5° .

The simulation results verify the availability that the beam from the laser diode meets the requirements after optical emission from system. Simulation was also made in a sequential mode just in case (Fig. 1.9).

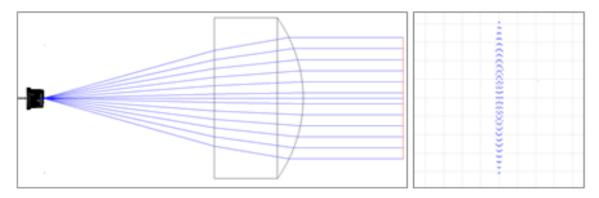


Fig. 1.9. Ray-traycing of single-lens collimator based on aspheric lens in sequential mode

As a result, the assembled compact laser collimator with an integrated OSRAM diode is shown in the Fig. 1.10. This collimator provide beam angular size is 0.1° x 2.5° , by having length only 10 mm, and diameter 6 mm.



Fig. 1.10. Assembled compact laser collimator

1.1.3 Laser driver

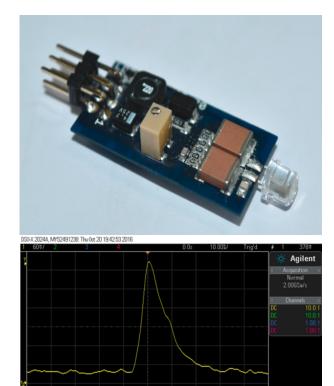


Fig. 1.11. Upper fig is laser driver with attached Osram diode. Bottom one is output of detector catched by 2GSa/s oscilloscope after laser shoot.

To operate Osram laser diode the laser driver is required. The simple one is shown in the upper part in Fig 1.11. This is commercial one, provides 40A at repetition rate up to 100kHz(?). The lower part shows the screenshot of the 2Gsa/s oscilloscope, as can be seen, the pulse duration is of the order of 10 ns. The detector was SiPM which is described in the next section.

Our team made an analog of this laser driver, smaller in size with the same characteristics, as well as with a combined detector (SiPM) part.

1.1.4 Final

Finally we got laser system with the following params: *table*

1.2 MEMS module

1.3 SiPM module

1.3.1 SiPM detector

1.3.2 SiPM collimator

AZAZAZA Their long-term aid [1] [2]

The Latex typesetting markup language is specially suitable for documents that include mathematics. Formulas are rendered properly an easily once one gets used to the commands.

Given a set of numbers, there are elementary methods to compute its Greatest Common Divisor,



References

- [1] L. Haggarty and B. Pepin. An investigation of mathematics textbooks and their use in english, french and german classrooms. *Proceedings of the British Society for Research into Learning Mathematics*, 21(2):117–125, 2001.
- [2] L. Haggarty and B. Pepin. An investigation of mathematics textbooks and their use in english, french and german classrooms. *Proceedings of the British Society for Research into Learning Mathematics*, 21(2):117–125, 2001.

A. Consectetur adipiscing elit

A.1 First part

asxdsdsa

A.2 Second

I'm a second part!

B. Mauris euismod

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